Solid State Equations BY: AUTHOR

Constants

Physical

q	Elementary Charge	1.602×10^{-19}	С
m_0	Electron Mass	9.11×10^{-19}	kg
ϵ_0	Permittivity of Free Space	8.854×10^{-14}	F/cm
μ_0	Permeability of Free Space	1.257×10^{-8}	H/cm
k	Boltzmann's Constant	1.38×10^{-23}	J/K
k	Boltzmann's Constant	8.62×10^{-5}	eV/K
h	Planck Constant	6.626×10^{-34}	Js
h	Planck Constant	4.136×10^{-15}	eVs
\hbar	Reduced Planck Constant	1.055×10^{-34}	$\mathrm{J}\mathrm{s}$
\hbar	Reduced Planck Constant	6.582×10^{-16}	eVs

Material

		Si	GaAs	Ge
ϵ_r		11.7	13.1	16.0
E_g	${ m eV}$	1.12	1.42	0.66
χ	V	4.01	4.07	4.13
N_c	cm^{-3}	2.8×10^{19}	4.7×10^{17}	1.04×10^{19}
N_v	cm^{-3}	1.04×10^{19}	7.0×10^{18}	6.0×10^{18}
n_i	${ m cm}^{-3}$	1.5×10^{10}	1.8×10^{6}	2.4×10^{13}

Equations

Carrier Concentration and Fermi Level

$$n_{0} = \frac{N_{D} - N_{A}}{2} + \left[\frac{N_{D} - N_{A}}{2} + n_{i}^{2}\right]^{1/2}$$

$$p_{0} = \frac{N_{A} - N_{D}}{2} + \left[\frac{N_{A} - N_{D}}{2} + n_{i}^{2}\right]^{1/2}$$

$$N_{c} = 2\left[\frac{m_{n}^{*}kT}{2\pi\hbar^{2}}\right]^{3/2} \qquad N_{v} = 2\left[\frac{m_{p}^{*}kT}{2\pi\hbar^{2}}\right]^{3/2}$$

$$n_{0} = n_{i} \exp\left[\frac{E_{F} - E_{i}}{kT}\right] \qquad p_{0} = n_{i} \exp\left[\frac{E_{i} - E_{F}}{kT}\right]$$

$$n_{0} = N_{c} \exp\left[\frac{-(E_{c} - E_{F})}{kT}\right] \qquad p_{0} = N_{v} \exp\left[\frac{-(E_{F} - E_{v})}{kT}\right]$$

$$E_{c} - E_{F} = -kT \ln \frac{N_{D}}{N_{c}} \qquad E_{F} - E_{v} = -kT \ln \frac{N_{A}}{N_{v}}$$

$$R - G_{t} = \frac{np - n_{i}^{2}}{\tau_{n}(n + n_{t}) + \tau_{p}(p + p_{t})}$$

$$n_{t} = n_{i} \exp\left(\frac{E_{t} - E_{i}}{kT}\right) \qquad p_{t} = n_{i} \exp\left(\frac{E_{i} - E_{t}}{kT}\right)$$

$$L_p = \sqrt{D_p \tau_p}$$
 $L_n = \sqrt{D_n \tau_n}$ $L_D = \sqrt{\frac{\epsilon_s kT}{q^2 N}}$

Carrier Transport

$$J_{\text{drift}} = \rho_p v_{dp} - \rho_n v_{dn}$$

$$v_{dp} = \mu_p \mathcal{E}$$
 $v_{dn} = -\mu_n \mathcal{E}$
$$\rho_p = qp \qquad \qquad \rho_n = -qn$$

$$J_{\text{drift}} = q(\mu_n n + \mu_p p) \mathcal{E} = \sigma \mathcal{E}$$

$$\frac{1}{2} m^* v_{sat}^2 = \frac{3}{2} kT$$

$$J_{\text{diff}} = -q \left(D_p \frac{dp}{dx} - D_n \frac{dn}{dx} \right) = -kT \left(\mu_p \frac{dp}{dx} - \mu_n \frac{dn}{dx} \right)$$

p-n Junctions

$$V_{bi} = |\phi_{Fp}| + |\phi_{Fn}| = \frac{kT}{q} \ln\left(\frac{N_A N_D}{n_i^2}\right)$$

$$W = \left[\frac{2\epsilon_s(V_{bi} - V_a)}{q} \left(\frac{N_A + N_D}{N_A N_D}\right)\right]^{1/2}$$

$$x_p = \left[\frac{2\epsilon_s(V_{bi} - V_a)}{q} \left(\frac{N_D}{N_A}\right) \frac{1}{N_A + N_D}\right]^{1/2}$$

$$x_n = \left[\frac{2\epsilon_s(V_{bi} - V_a)}{q} \left(\frac{N_A}{N_D}\right) \frac{1}{N_A + N_D}\right]^{1/2}$$

$$\mathcal{E}_{max} = \frac{-qN_D x_n}{\epsilon_s} = \frac{-qN_A x_p}{\epsilon_s}$$

$$\mathcal{E}_{max} = \frac{-2(V_{bi} - V_a)}{W}$$

$$np = n_i^2 \exp\left(\frac{qV_a}{kT}\right)$$

$$\delta p_n(x) = p_n(x) - p_{n0} = p_{n0} \left[\exp\left(\frac{qV_a}{kT}\right) - 1\right] \exp\left(\frac{x_n - x}{L_p}\right)$$

$$J_0 = \left(\frac{qD_n p_{n0}}{L_p} + \frac{qD_n n_{p0}}{L_n}\right)$$

$$J = J_0 \left[\exp\left(\frac{qV_a}{kT}\right) - 1\right]$$

$$C'_{ox} = \frac{\epsilon_{ox}}{t_{ox}}$$

$$C'_{sc} =$$

Schottky Junction

$$V_{bi} = \underbrace{\phi_m - \chi}_{\phi_{Bn}} - \underbrace{kT \ln(N_c/N_d)}_{\phi_n}$$
$$x_n = \left[\frac{2\epsilon_s(V_{bi} - V_a)}{qN_D}\right]^{1/2}$$

MOS Capacitors

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